REVISIONS DATE **APPROVED** LTR DESCRIPTION mall June 9, Α Change to military drawing format. Changes in table I tests and condi-1987 tions. Delete vendor CAGE 27014. Editorial changes throughout. REV PAGE REV A A Α Α Α A A **REV STATUS OF PAGES** PAGES 1 2 3 4 5 6 8 9 10 11 PREPARED BY **Defense Electronics** Marcia B. Kelleher **Supply Center** This drawing is available for use by Dayton, Ohio CHECKED BY all Departments and Agencies of the Department of Defense TITLE: MICROCIRCUITS, LINEAR, Original date OPERATIONAL AMPLIFIER, MONOLITHIC SILICON of drawing: 20 Sept, 77 CODE IDENT. NO. SIZE DWG NO. 77039 14933 Α AMSC N/A REV PAGE OF 1 Α 11 5962-E377

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

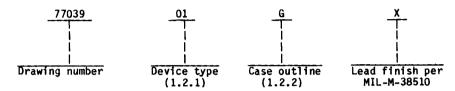
DESC FORM 193

MAY 86

| SCOPE |
|-------|
| |
| |

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device type. The device type shall identify the circuit function as follows:

| Device type | Generic number | Circuit function |
|-------------|----------------|-----------------------|
| 01 | 4250 | Operational amplifier |

1.2.2 <u>Case outlines</u>. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter

G
H
F-4, (8-lead can)
F-4, (10-lead, 1/4" x 1/4"), flat package
D-4, (8-lead, 1/4" x 3/8"), dual-in-line package

1.3 Absolute maximum ratings.

| Supply voltage (V _{SS}) | ±18 V dc |
|--|-------------------------------|
| Power dissipation (PD) $\underline{1}/$ | 500 mW |
| Differential input voltage | ±30 V dc |
| Input voltage 2/ | ±15 V dc |
| Icer current | 150 μA |
| Oŭtout short-circuit duration | Indefinite |
| Storage temperature range | -65°C to +150°C |
| Lead temperature (soldering, 10 seconds) | +300°C |
| Junction temperature (T_J) | +150°C |
| Thermal resistance (0 _{JC}): | |
| Cases G, H, P | (See MIL-M-38510, appendix C) |
| Thermal resistance (O JA): | |
| Case G | 150°C/W |
| Case P | 125°C/W |

1.4 Recommended operating conditions.

Ambient operating temperature range - - - - - - - - - - - - - - - - - 55°C to +125°C

1/ Must withstand the added P_D due to short-circuit test (e.g., I_{OS}).

 $\frac{2}{2}$ For $V_{SS} \leq \pm 15$ V, absolute maximum input voltage is equal to supply voltage.

| MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO | SIZE A | 14933 | DWG NO. 77039 |
|---|-----------|-------|------------------|
| | | REV A | PAGE 2 |



2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

| MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO | SIZE A | | 333 | NO. | DWG NO | 77039 | |
|---|-----------|---|-----|-----|--------|-------|---|
| | | R | EV | A | | PAGE | 3 |

| Test | Symbol | Condi -55°C < TA unless other | tions < +125°C wise specified | Group A subgroups | Limi Min | ts Max | Unit |
|----------------------|------------------|---|--|----------------------|--------------|-----------|------|
| nput offset voltage | v _{os} | $V_S = \pm 1.5 \text{ V}$ $R_S = < 100 \text{ kg}$ | $\begin{array}{c} I \\ I \\ SET = 1 \\ \underline{1}/ \end{array}$ | 1 | | 6 | m۷ |
| | ļ | ! | | 2,3 | | 7.5 | mV |
| | | | I _{SET} = 10 μA | 1 | | 6 | m۷ |
| | i I | | <u>-</u> ' | 2,3 | i i | 7.5 | mV |
| Input offset current | l ₀ s | V _S = ±1.5 V | I _{SET} = 1 μA | 1,3 | | 6 | nA |
| | | ! | <u>'</u> ' | 2 | | 8 | nA |
| | | | I _{SET} = 10 μA 1 | 1,2,3 |] | 25 | nA |
| | | V _S = ±15 V | I _{SET} = 1 μA | 1,3 | | 6 | nA |
| | i | | 1/ | 2 | i i | 8 | nA |
| | ! | | I _{SET} = 10 μA | 1,3 | | 20 | nA |
| | İ | | 1 -1 | 2 | | 25 | nA |
| Bias current | Ibias | V _S = ±1.5 V | I SET = 1 μA 1 | 1,2,3 | | 10 | nA |
| | 1 ! | 1 | I _{SET} = 10 μA 1 | 1,2,3 | | 80 | nA |
| | ! ! [| V _S = ±15 V R _S < 100 ko | $I_{SET} = \frac{1}{1} \mu A$ | 1,2,3 | | 10 | nA |

See footnote at end of table.

| MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO | SIZE | 10ENT | _ | DWG NO. | 77039 | |
|---|------|-----------|---|---------|-------|---|
| | | REV | A | | PAGE | 4 |

| Test | Symbol | Cond -55°C < unless othe | itions T _{A <} +125°C rwise specified | Group A subgroups | ! Limi Min | ts Max | Unit |
|---------------------------|----------------|---|---|----------------------------|--------------------------|-----------------|--------------------------|
| Large signal voltage gain | Avs | $ V_S = \pm 1.5 \text{ V} V_0 = \pm 0.6 \text{ V}$ | I _{SET} = 1 μA 1/ R _L = 100 kΩ | 1 | 25k | | |
| | İ | | 1 | 2 | 20k | | |
| | 1 | | I _{SET} = 10 μA | 1 | 25k | | |
| | į | | 1 1/ | 2 | 20k | | |
| | | $V_S = \pm 1.5 V$ $V_0 = \pm 0.5 V$ | I _{SET} = 1 μA 1/ R _L = 100 kΩ | 1,3 | 25k | | |
| | | | ISET = 10 μA 1/ RL = 10 k° | 1,3 | 25k | | · |
| | | V _S = ±15 V V _O = ±10 V | I _{SET} = 1 μA 1/ R _L = 100 kΩ | 1 2,3 | 60k 50k | | |
| | | | ISET = 10 μA 1/ | 1 2,3 | 60k 50k | | |
| Power consumption | <u> </u> | V _S = ±1.5 V | I _{SET} = 1 μA <u>1</u> / | 1 2,3 | | 24 | μW Wμ |
| | • | ! ! | I _{SET} = 10 μA 1/ | 1 2,3 | | 270 270 | μW |
| | | V _S = ±15 V | ISET = 1 μA | 1 2,3 | | 300 330 | μ W μ W |
| | | | I _{SET} = 10 μA | 1 2,3 | | 2.7 | Wm Wm |
| Input voltage range | VIR | V _S = ±1.5 V | I _{SET} = 1 μA <u>1</u> / | 1,2,3 | ±0.6 | | ٧ |
| | | []] | I _{SET} = 10 μA 1/ | 1,2,3 | ±0.6 | | ٧ |
| | | V _S = ±15 V | ISET = 1 μA 1/ | 1,2,3 | ±13.5 | | ٧ |
| | ŀ | ! ! | I _{SET} = 10 μA 1/ | 1,2,3 | ±13.5 | Ţ | ٧ |

CODE IDENT. NO. SIZE DWG NO. **MILITARY DRAWING** 14933 77039 DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO REV PAGE A 5

| Test | Symbol | Condit -55°C < T _A unless other | ions < +125°C wise specified | Group A | Limits Min Max | Unit |
|---|-----------------|--|--|-------------------|-------------------------------|----------------|
| Output voltage swing | V _{OH} | V _S = ±1.5 V | ISET = 1 μ A 1/2 R _L = 100 kΩ T _A = +125°C | / 2 | | ٧ |
| | | | ISET = 1 μA 1/2 RL = 100 kΩ -55°C <ta<+25°c< td=""><td>1,3</td><td> </td><td>V[']</td></ta<+25°c<> | 1,3 | | V ['] |
| | ! ! ! | | ISET = 10 μA 1. R _L = 10 kΩ T _A = +125°C | 2 | | V |
| | | ! ! ! | ISET = 10 μA 1. RL = 10 kΩ -55°C <ta<+25°c< td=""><td>/ / 1,3</td><td> ±0.6</td><td>V</td></ta<+25°c<> | / / 1,3 | ±0.6 | V |
| | | V _S = ±15 V | ISET = 1 μA 1. | 1,2,3 | ±12 | ٧ |
| | | ! - | ISET = 10 μA 1. | 1,2,3 | | ٧ |
| Common mode rejection ratio | CMRR | V _S = ±1.5 V | I _{SET} = 1 μA <u>1</u> | 4,5,6 | 70 1 | dB |
| | | R _S ≤ 10 kΩ | I _{SET} = 10 μA 1. | 4,5,6 | | dB |
| | ! ! ! | V _S = ±15 V | ISET = 1 μA <u>1</u> | 4,5,6 | 70 | dB |
| | ! ! | Rs <u><</u> 10 ko | ISET = 10 μA 1 | 4,5,6 | 70 70 | dB |
| Supply voltage rejection ratio | PSRR | V _S = ±1.5 V | I _{SET} = 1 μA <u>1</u> | 4,5,6 | 65 | dB |
| | | R _S <u><</u> 10 kΩ | I _{SET} = 10 μA 1 | 4,5,6 | 65 | dB |
| | . | V _S = ±15 V | ISET = 1 μA 1 | 4,5,6 | 74 | dВ |
| | ! | R _S <u><</u> 10 kΩ | ISET = 10 μA 1 | 4,5,6 | 74 | dB |
| e footnote at end of table. | | | | | | |
| MILITARY DRAWI | | | 14933 | NG NO. | 039 | |
| DEFENSE ELECTRONICS SUPPLY DAYTON, OHIO | CENTER | • | REV A | PAG | 6 E | |

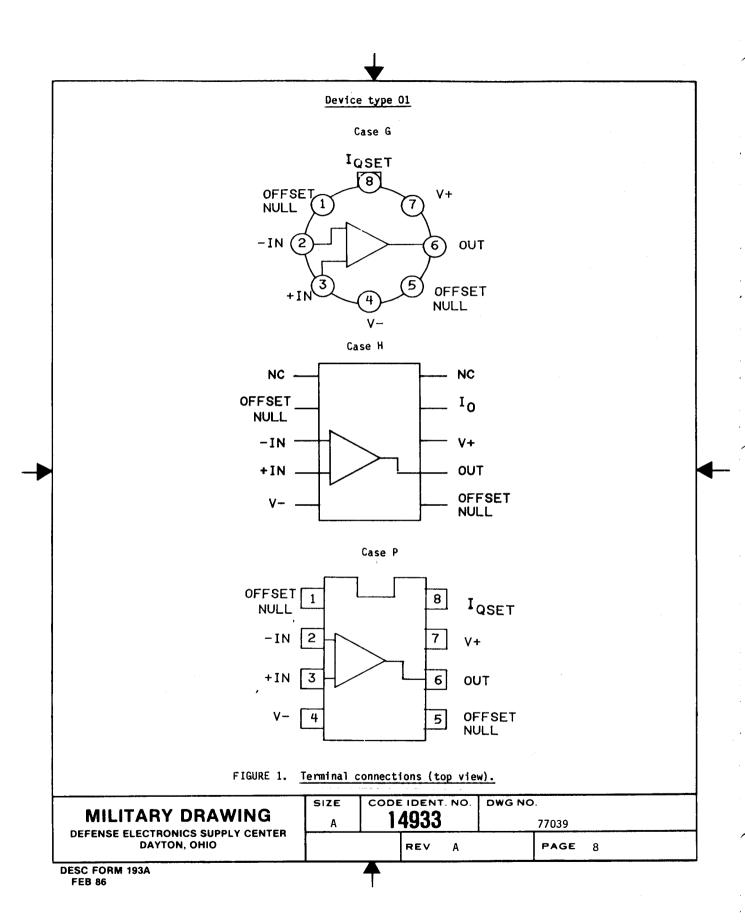
| | 1 | |
|---|---|---|
| _ | 1 | _ |
| 7 | | ı |

| Test | [Symbo] | Cond | itions | Group A | Limi | | Unit |
|----------------|----------------|-----------------------------------|-------------------------------|---------|------|----------|----------------------|
| | | -55°C < T unless other | subgroups | Min | Max | <u> </u> | |
| Supply current | Icc | V _S = ±1.5 V | I _{SET} = 1 μA | 2,3 | | 7.5 8 | μ Α |
| | | | I _{SET} = 10 μA | 1 2,3 | | 80 90 | Ι Ι μΑ Ι |
| | | V _S = ±15 V | I _{SET} = 1 μA 1/ | 1 2,3 | | 10 11 | μ Α |
| | | | I _{SET} = 10 μA | 1 1 2,3 | i | 90 | μА |

1/ Resistor biasing, set current setting resistor to V-.

| | I _{SET} | | | | | | | | |
|----------------|------------------|---------|---------|---------|---------|--|--|--|--|
| V _S | 0.1 μA | 0.5 μA | 1.0 μΑ | 5 μΑ | 10 μΑ | | | | |
| 1.5 V | 25.6 MΩ | 5.04 MΩ | 2.5 MΩ | 492 kΩ | 244 kΩ | | | | |
| ±3.0 V | 55.6 MΩ | 11.0 MΩ | 5.5 MΩ | 1.09 MΩ | 544 kΩ | | | | |
| ±6.0 V | 116 MΩ | 23.0 MΩ | 11.5 MΩ | 2.29 MΩ | 1.14 ΜΩ | | | | |
| ±9.0 V | 176 MΩ | 35.0 MΩ | 17.5 MΩ | 3.49 MΩ | 1.74 ΜΩ | | | | |
| ±12.0 V | 236 MΩ | 47.0 MΩ | 23.5 MΩ | 4.69 MΩ | 2.34 MΩ | | | | |
| ±15.0 V | 296 MΩ | 59.0 MΩ | 29.5 MΩ | 5.89 MΩ | 2.94 MΩ | | | | |

| MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO | SIZE A | 1933 | DWG NO | DWG NO. 77039 | | |
|---|-----------|------|--------|------------------|---|--|
| | | REV | | PAGE | 7 | |



- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - Burn-in test (method 1015 of MIL-STD-883).
 - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 7, 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

| MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO | SIZE A | 14933 | . NO. | DWG NO. | 77039 | |
|---|-----------|-------|-------|---------|-------|---|
| | | REV | A | | PAGE | 9 |

TABLE II. Electrical test requirements.

| MIL-STD-883 test requirements | Subgroups (per method 5005, table I) |
|--|--|
| Interim electrical parameters (method 5004) | |
| Final electrical test parameters (method 5004) | 1*,2,3 |
| Group A test requirements (method 5005) | 1,2,3,4,5,6 |
| Groups C and D end-point electrical parameters (method 5005) | 1 |

^{*} PDA applies to subgroup 1.

- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
- 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

| MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO | SIZE A | 14933 | D w G NO. 77039 | | |
|---|-----------|-------|---------------------------|----|--|
| | | REV A | PAGE | 10 | |

6.4 Approved source of supply. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

| Military drawing part number | Vendor CAGE number | Vendor similar part number <u>1</u> / | Replacement military specification part number |
|------------------------------|------------------------------|---|---|
| 7703901GX | 32293 | LM4250H | |
| 7703901HX <u>2</u> / | | | |
| 7703901PX | 32293 | LM4250J | |

Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
This part not available at this time from approved sources.

Vendor CAGE number

32293

Vendor name and address

Intersil, Incorporated 10900 North Tantau Avenue Cupertino, CA 95014

| MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO | SIZE A | 14933 | DWG NO. 77039 | |
|---|-----------|-------|------------------|---|
| | | REV A | PAGE 1 | 1 |